

VASAVI COLLEGE OF ENGINEERING (AUTONOMOUS) DEPARTMENT OF PHYSICS PHYSICS OE TRACKS (B.E-III Semester) Semiconductor Physics and Device Applications ESSENTIALS OF SEMICONDUCTOR PHYSICS

L:T:P	Credits	CIE		SEE		Course Code
		Marks	Exam	Marks	Exam	
			Duration		Duration	
02 :0 :0	2	30	90 min	60	3hours	U230E320PH
CIE	Assignments (02)		Quizzes (02)	Internal Exams(01)		Total CIE Marks
Ave. Marks	5		5	30		40

UNIT I: Basics of Quantum Mechanics (8 Hrs)

Existence of matter waves, Wave function and its significance, Schrodinger time dependent and independent wave equations, Wave equation of a free particle, Origin of band gap, Energy bands in solids, Postulates of quantum mechanics, Quantum mechanical operators and expectation values, Potential well, Quantum tunnelling.

UNIT II: Semiconductors: Energy Band and Charge Carriers (6 Hrs)

Types of semiconductors (doping, bandgap, composition), Fermi-Dirac statistics- Density of states of semiconductor, Fermi level in semiconductors, Law of mass action, Charge compensation and charge neutrality, Hall probes and its applications.

UNIT-III: Growth of Semiconductors (6 Hrs)

Introduction, Bulk crystal growth, Epitaxial crystal growth, Evaporation and sputtering, defects in crystal, Band gap engineering, GaAs crystal growth.

UNIT IV: Carrier Transport in Semiconductors (6 Hrs)

Carrier generation, Carrier life time, Carrier scattering and mobility, Low-field and high-field transport, introduction to diffusion, Drift-diffusion current and total current density, Einstein relation, Direct and indirect recombination and trapping, Current continuity equation, Carrier injection, ambipolar transport, Diffusion length.

References:

1.P. Bhattacharya, Semiconductor Optoelectronic Devices, Prentice Hall of India (1997).

- 2. Donald Neamen, Semiconductors Physics and Devices, Tata Mc Graw Hill, 2003
- 3. Tyagi, Introduction to Semiconductor Materials and Devices, Wiley Publications, 2002.
- 4. Semiconductor Devices, Basic Principles Jasprit Singh, Wiley Publications, 2001
- 5. Electronic Devices and Circuits- Millman and Halkias-Tata Mc Graw Hill, 1983.
- 6. Solid State Electronic Devices Ben G Streetman-Prentice Hall, New Delhi, 1995.

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